

Product Summary

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
250V	35mΩ@10V	48A

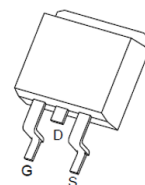
Feature

- Split Gate Trench Technology
- Low $R_{DS(on)}$
- Low Gate Charge
- Low Gate Resistance
- 100% UIS Tested

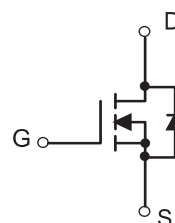
Application

- Motor Control
- DC/DC Converter

TO-263-2L



Schematic diagram



Package Marking and Ordering Information

Part Number	Package	Marking	Packing	Reel Size	Tape Width	Qty
GPT350N25NTH	TO-263-2L	T350N25N	Reel & Tape	330mm	24mm	800pcs

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Parameter		Symbol	Value	Unit
Drain-Source Voltage		V_{DS}	250	V
Gate-Source Voltage		V_{GS}	±20	V
Continuous Drain Current ¹	$T_C = 25^\circ\text{C}$	I_D	48	A
	$T_C = 100^\circ\text{C}$		30	
Pulsed Drain Current ²		I_{DM}	192	A
Single Pulsed Avalanche Current ³		I_{AS}	32	A
Single Pulsed Avalanche Energy ³		E_{AS}	256	mJ
Power Dissipation ⁵	$T_C = 25^\circ\text{C}$	P_D	278	W
Thermal Resistance from Junction to Ambient ⁶		$R_{\theta JA}$	62	$^\circ\text{C/W}$
Thermal Resistance from Junction to Case		$R_{\theta JC}$	0.45	$^\circ\text{C/W}$
Junction Temperature		T_J	150	$^\circ\text{C}$
Storage Temperature		T_{STG}	-55~ +150	$^\circ\text{C}$

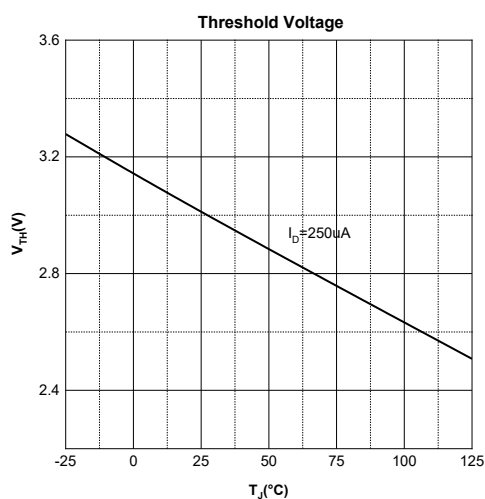
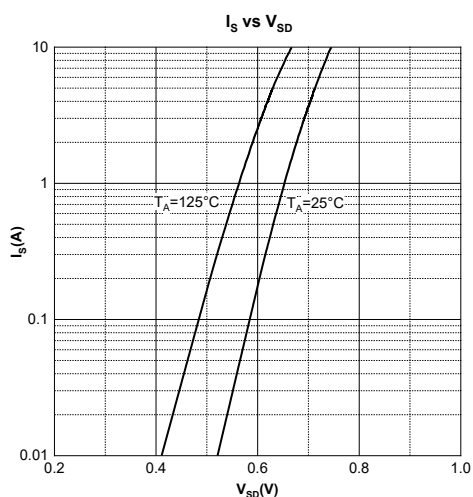
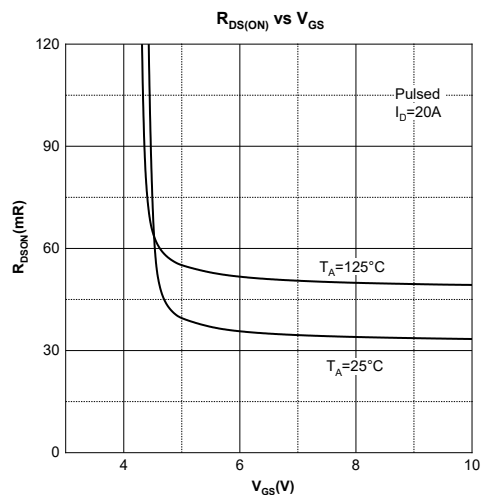
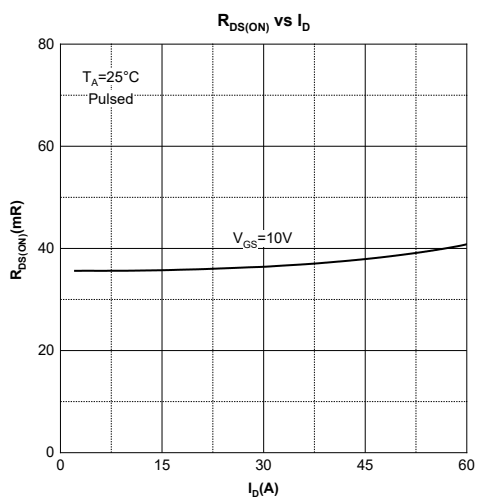
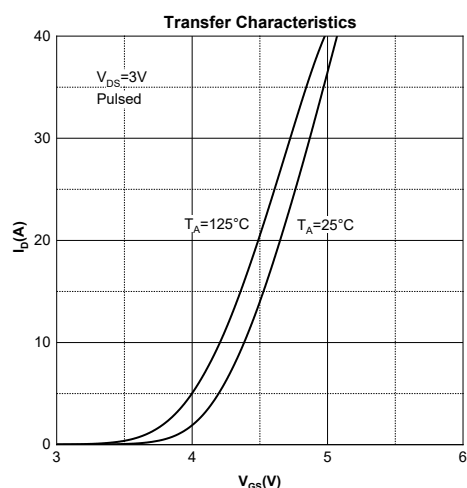
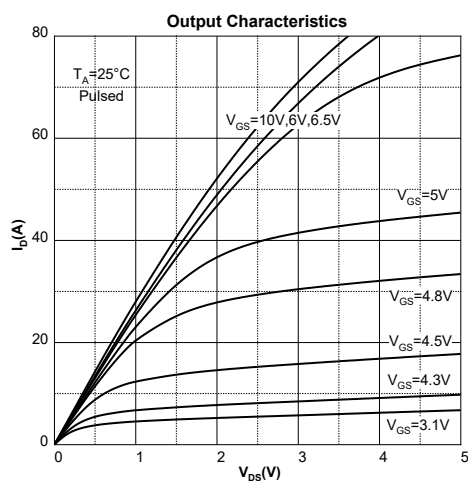
MOSFET ELECTRICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$ unless otherwise noted)

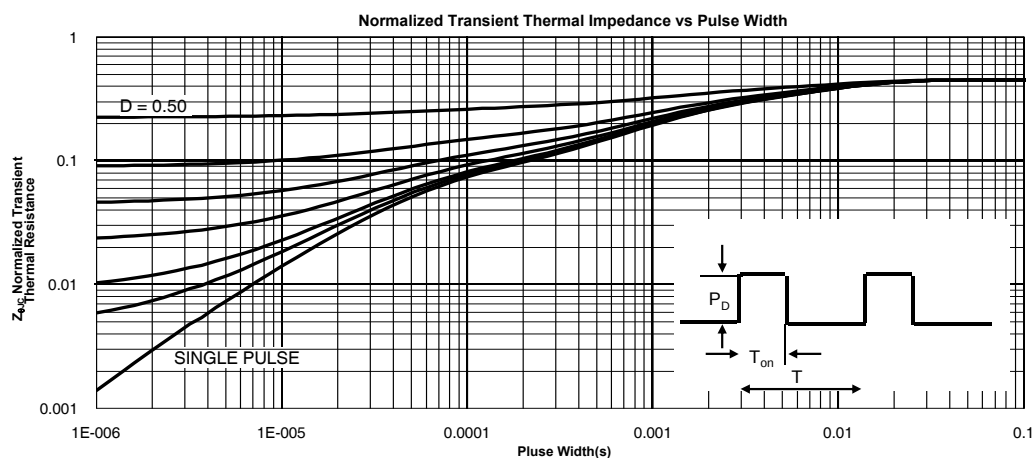
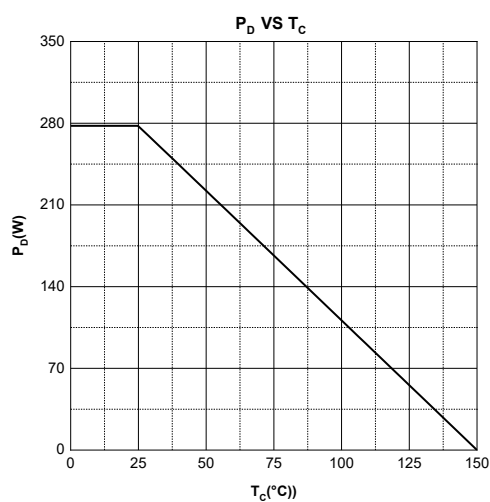
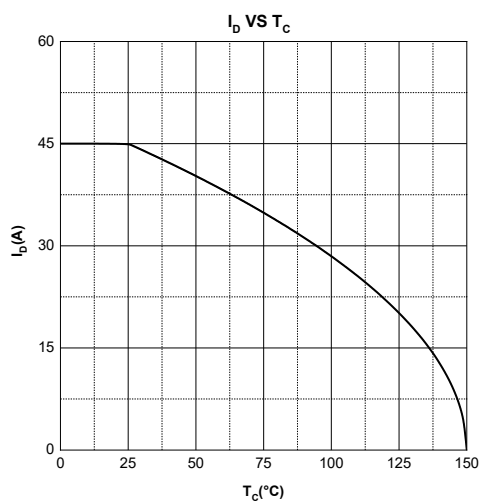
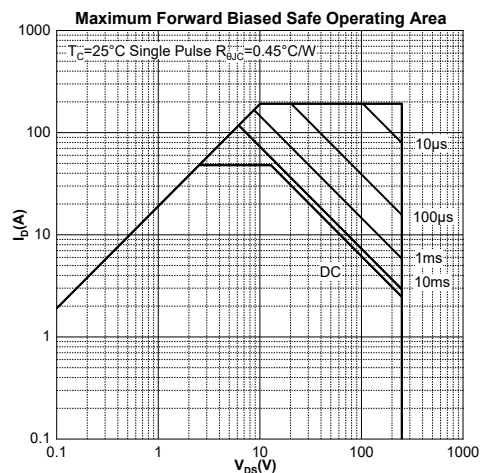
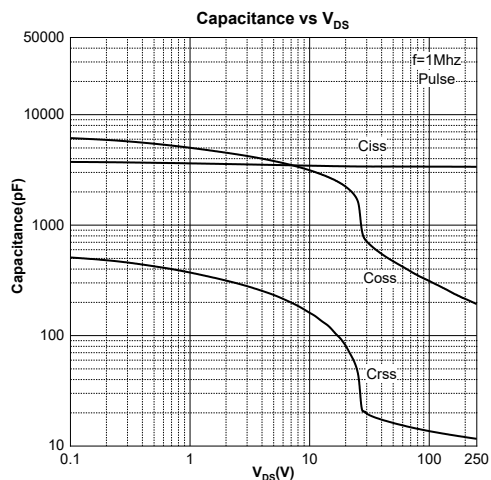
Parameter	Symbol	Test Condition	Min	Type	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	250			V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 250V, V_{GS} = 0V$			1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{GS} = \pm 20V, V_{DS} = 0V$			± 100	nA
On Characteristics ⁴						
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	2	3	4	V
Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 10A$		35	45	m Ω
Dynamic Characteristics						
Input Capacitance	C_{iss}	$V_{DS} = 125V, V_{GS} = 10V,$ $f = 0.1MHz$		3384		pF
Output Capacitance	C_{oss}			275		
Reverse Transfer Capacitance	C_{rss}			16		
Gate Resistance	R_g	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$		4		Ω
Switching Characteristics						
Total Gate Charge	Q_g	$V_{DS} = 150V, V_{GS} = 10V, I_D = 10A$		50		nC
Gate-Source Charge	Q_{gs}			15		
Gate-Drain Charge	Q_{gd}			12		
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 125V, V_{GS} = 10V, I_D = 26A,$ $R_G = 2.4\Omega$		16		ns
Turn-On Rise Time	t_r			27		
Turn-Off Delay Time	$t_{d(off)}$			25		
Turn-Off Fall Time	t_f			19		
Source-Drain Diode Characteristics						
Diode Forward Voltage ⁴	V_{SD}	$V_{GS} = 0V, I_S = 10A$			1.2	V

Notes:

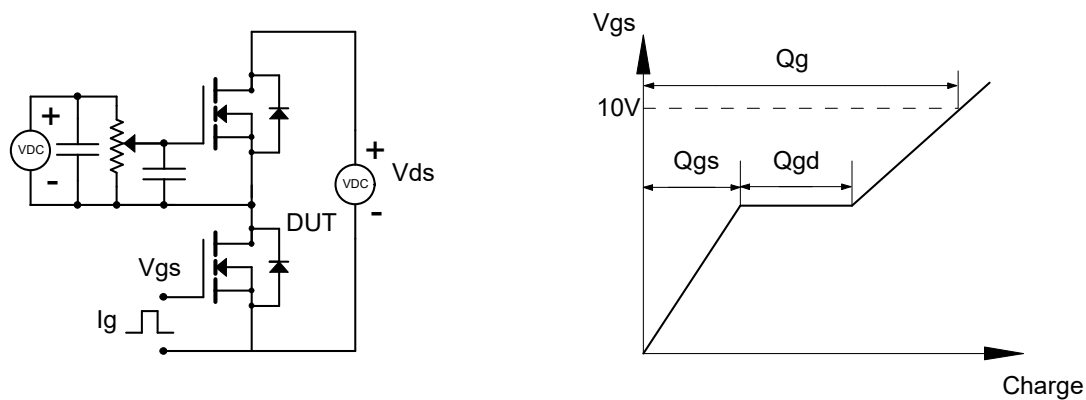
- 1.The maximum current rating is limited by package. And device mounted on a large heatsink.
- 2.Pulse Test: Pulse Width $\leq 10\mu s$, duty cycle $\leq 1\%$.
- 3.EAS condition: $V_{DD} = 100V, V_{GS} = 10V, L = 0.5mH, R_G = 25\Omega$ Starting $T_J = 25^\circ\text{C}$.
- 4.Pulse Test: Pulse Width $\leq 300\mu s$, duty cycle $\leq 2\%$.
- 5.The power dissipation P_D is limited by $T_{J(MAX)} = 150^\circ\text{C}$. And device mounted on a large heatsink.
- 6.Device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A = 25^\circ\text{C}$.

Typical Characteristics

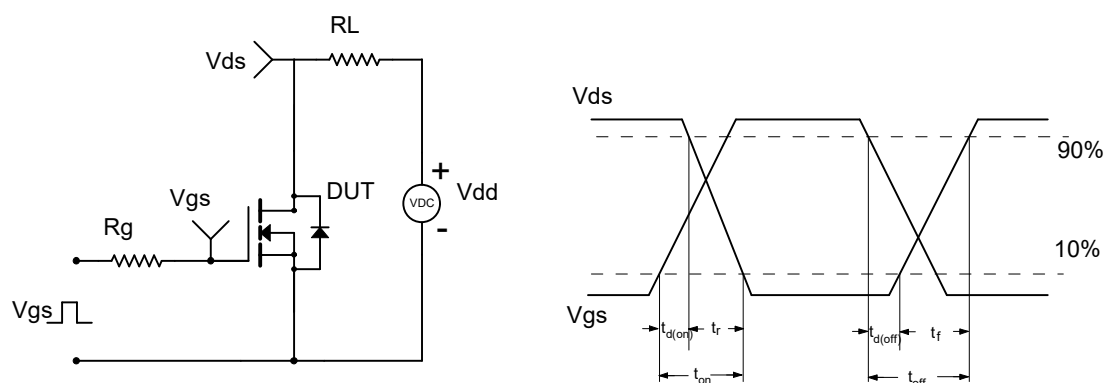




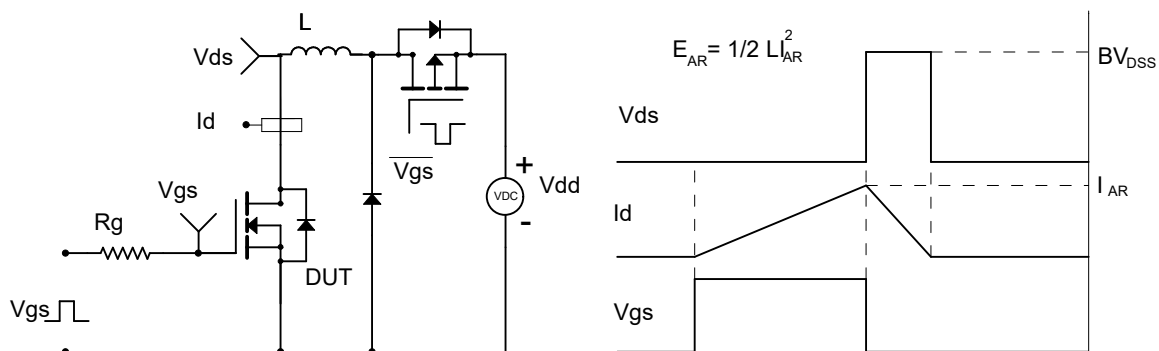
Gate Charge Test Circuit & Waveform

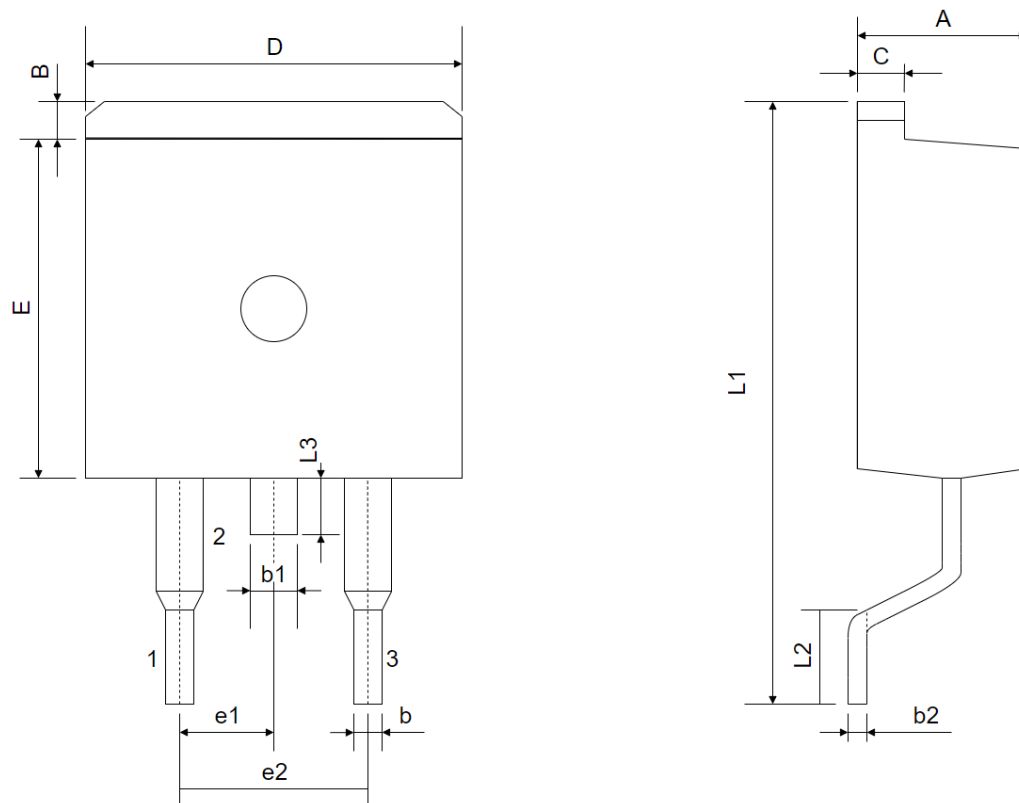


Resistive Switching Test Circuit & Waveform



Unclamped Inductive Switching (UIS) Test Circuit & Waveforms



TO-263-2L Package Information


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	4.300	4.700	0.169	0.185
B	1.000	1.400	0.039	0.055
b	0.700	0.900	0.028	0.035
b1	1.150	1.40	0.045	0.053
b2	0.400	0.600	0.016	0.024
C	1.200	1.400	0.047	0.055
D	9.680	10.200	0.381	0.402
E	9.000	9.400	0.354	0.370
e1	2.340	2.740	0.092	0.108
e2	4.880	5.280	0.192	0.208
L1	14.800	16.000	0.582	0.630
L2	2.100	2.840	0.083	0.112
L3	1.100	1.600	0.043	0.063

Attention:

- GreenPower Electronics reserves the right to improve product design function and reliability without notice.
- Any and all semiconductor products have certain probability to fail or malfunction, which may result in personal injury, death or property damage. Customer are solely responsible for providing adequate safe measures when design their systems.
- GreenPower Electronics products belong to consumer electronics or other civilian electronic products.